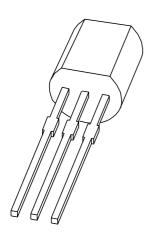
DISCRETE SEMICONDUCTORS

DATA SHEET



BB212 AM variable capacitance double diode

Product specification
Supersedes data of April 1992
File under Discrete Semiconductors, SC01

1996 May 03





AM variable capacitance double diode

BB212

FEATURES

- · Leaded plastic package
- C8: 19 pF; ratio: 29.

APPLICATIONS

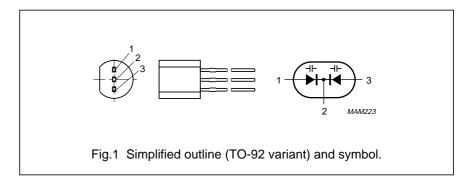
- Electronic tuning in AM radio applications
- VCO.

DESCRIPTION

The BB212 is a variable capacitance double diode with a common cathode, fabricated in planar technology, and encapsulated in the TO-92 variant leaded plastic package.

PINNING

| PIN | DESCRIPTION |
|-----|----------------|
| 1 | anode (a1) |
| 2 | common cathode |
| 3 | anode (a2) |



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT | | |
|------------------|--------------------------------|------|------|------|--|--|
| Per diode | | | | | | |
| V _R | continuous reverse voltage | | 12 | V | | |
| I _F | continuous forward current | _ | 100 | mA | | |
| T _{stg} | storage temperature | | +100 | °C | | |
| Tj | operating junction temperature | -55 | +85 | °C | | |

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AM variable capacitance double diode

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ELECTRICAL CHARACTERISTICS

 $T_i = 25$ °C; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT | | |
|-----------------------------|-------------------------|--|------|------|------|------|--|--|
| Per diode | | | | | | | | |
| I _R | reverse current | V _R = 10 V; see Fig.3 | _ | _ | 50 | nA | | |
| | | V _R = 10 V; T _j = 85 °C; see Fig.3 | - | _ | 300 | nA | | |
| r _s | diode series resistance | f = 500 MHz; note 1 | | | 2.5 | Ω | | |
| C _d | diode capacitance | see Figs 2 and 4 | | | | | | |
| | | V _R = 0.5 V; f = 1 MHz | 500 | - | 620 | pF | | |
| | | V _R = 3 V; f = 1 MHz | 140 | - | 280 | pF | | |
| | | V _R = 5.5 V; f = 1 MHz | 40 | _ | 90 | pF | | |
| | | V _R = 8 V; f = 1 MHz | _ | _ | 22 | pF | | |
| C _{d (0.5V)} | capacitance ratio | f = 1 MHz | 22.5 | _ | _ | | | |
| $\frac{d(0.5V)}{C_{d(8V)}}$ | | | | | | | | |

Note

1. V_R is the value at which $C_d = 500$ pF.

MATCHING PROPERTIES

The capacitance of the two diodes in their common package may differ within certain limits. The total, relative capacitance difference between the two diodes in one package may be found in Fig.5. The anode a1 or a2 with the higher capacitance at $V_R = 3\ V$, is identified by a white dot.

BASIC TOLERANCE

The relative deviation of the capacitance value at $V_R = 0.5 \ V$ is maximum 3.5%.

$$k = \left| \frac{C_1 (0.5 \, \text{V}) - C_2 (0.5 \, \text{V})}{C_2 (0.5 \, \text{V})} \right| = <3.5\%$$

ADDITIONAL TOLERANCE (see Fig.5)

In the range of $V_R = 0.5 \text{ V}$ to 8 V the following additional tolerances are valid.

$$S = \left| \left(\frac{C_1}{C_2} \right) V_R - \left(\frac{C_1}{C_2} \right) 0.5 V \right|$$

S < 2% for $V_R = 0.5$ to 3 V

S < 4% for $V_R = 3$ to 5.5 V

S < 6% for $V_R = 5.5$ to 8 V.

 C_1 is the capacitance of a1 when a1 > a2.

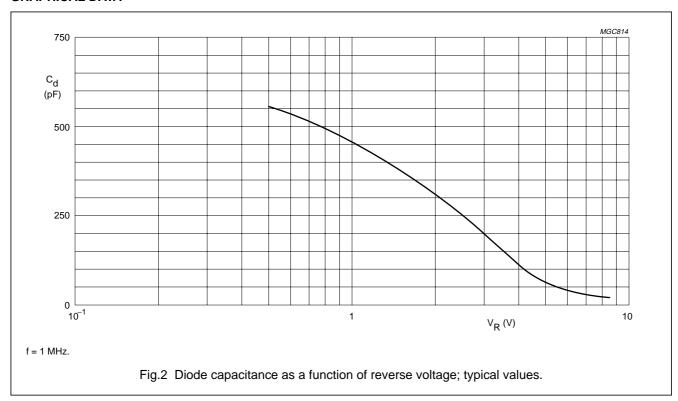
 C_1 is the capacitance of a2 when a2 > a1.

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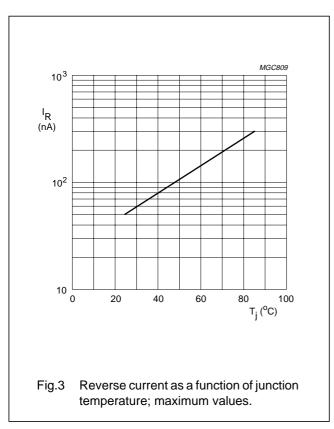
AM variable capacitance double diode

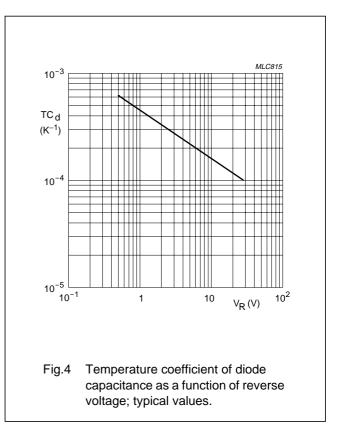
BB212

GRAPHICAL DATA



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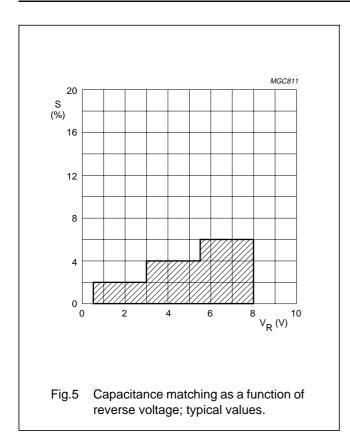




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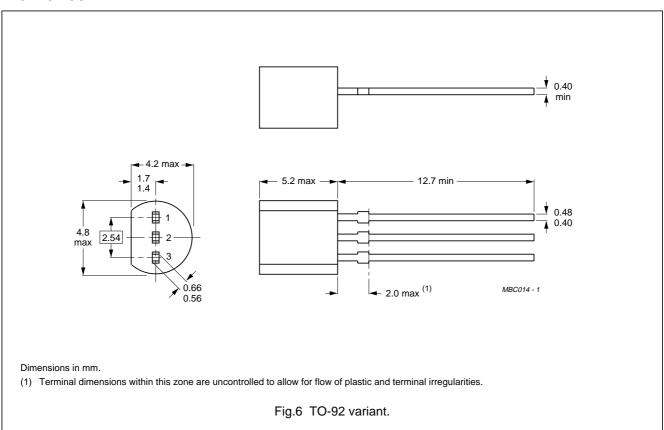
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Product specification Philips Semiconductors

AM variable capacitance double diode

PACKAGE OUTLINE



DEFINITIONS

| Data sheet status | | |
|---------------------------|---|--|
| Objective specification | This data sheet contains target or goal specifications for product development. | |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. | |
| Product specification | This data sheet contains final product specifications. | |
| Limiting values | | |

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification

Application information

Where application information is given, it is advisory and does not form part of the specification.

is not implied. Exposure to limiting values for extended periods may affect device reliability.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

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